



# RESEARCH OF AC-LGAD STRIP DETECTOR

# FOR 4D TRACKING

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## LGAD and AC-LGAD



• Radiation hardness:  $10^{15}$ ~ $10^{16}n_{ea}/cm^2$ 

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 $\rightarrow$  the ratio S/N becomes worse at higher gain

Noise increases faster than then signal

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## Motivation

LGAD based silicon sensors can provide precise timing information, while AC-LGAD as a new 4D detector, can provide the position information at the same time.

### DRDT 3.2 - Develop solid state sensors with 4D-capabilities for tracking and calorimetry

Understanding the ultimate limit of precision timing in sensors, with and without internal multiplication, requires extensive research and developments to increase radiation tolerance and achieve 100% fill factors. New semiconductor and technology processes with faster signal development and low noise readout properties should also be investigated

$\frac{\mathbf{WG2}}{\mathbf{WG2}} \text{ research goals } < 2027$		
	Description	
RG 2.1	Reduction of pixel cell size for 3D sensors	
RG 2.2	3D sensors for timing ( $\leq 55 \times 55 \ \mu m, < 50 \ ps$ )	
RG 2.3	LGAD for 4D tracking $<$ 10 $\mu {\rm m},$ $<$ 30 ps, wafer 6" and 8"	
RG 2.4	LGAD for ToF (Large area, $< 30 \ \mu m, < 30 \ ps$ )	

- RG 2.3: LGAD Sensors with very high fill factor, and an excellent spatial and temporal resolution.
  - 2024-2025: LGAD test structures of different technologies (TI-LGAD, iL-GAD, AC-LGAD/RSD, DJ-LGAD), matching existing read-out ASICs.
  - 2026-2028: Large LGAD sensors based on the best-performing technology.
  - 2025-2028: Investigation of radiation hardness of LGAD technology beyond  $\sim 2.5 \cdot 10^{15} \ n_{eq}/cm^2.$

#### • RG 2.4: LGAD sensors for Time-of-Flight applications

- 2024-2026: Production of LGAD sensors with large size for Tracking/Timeof-Flight applications to demonstrate yield and doping homogeneity. Study of spatial and temporal resolutions as a function of the pixel size.
- 2026-2028: LGAD structures with 4D capabilities produced with vendors capable of large-area productions to demonstrate the industrialization of the process.

 $\succ$  The project has been proposed at 1<sup>st</sup> DRD3 meeting.

Develop LGAD based silicon sensors and detector modules for the outer tracker and time-of-flight layer in future colliders (CEPC, FCC-ee, ILC, CLIC, etc.)

## **AC-LGAD** Research in IHEP



AC-LGAD R&Dv1:



Pixeled AC-LGAD
With different pad-pitch size
1000-2000um
100-500um
100-200um
50-100um
•wafers: with different n+ dose: 10P to 0.2P
Process parameters have been studied.



AC-LGAD R&Dv2:



Pixeled and strip AC-LGAD
With different pad-pitch size
1000-2000um pixel
100-250um strip
100-150um strip
50-100um strip
•wafers: with different n+ dose:0.2P to0.01P
First trial in AC-LGAD Strip

## **AC-LGAD** Strip

### **AC-LGAD Strip:**

- Position information: 2 layer •
- Strip length 5.6mm, width 100um •
- Different Pitch size: •

Spatial resolution

150um、200um、250um 





#### Picosecond laser scanning system

- Displacement accuracy 1 µm
- Automated scanning
- Picosecond laser 1064nm
- Spot size 2~5 µm





Beta source test system

- Stronium-90 2MeV MIP
- With trigger LGAD



## Signal properties and spatial resolution



0.58 0.56 Ch 1/(Ch 1+Ch 2) 0.54 Ch 2/(Ch 1+Ch 2) 0.52 0.5 <sup>iji</sup> 0.48 0.46 0.44 - Strip 1 Strip 2 and and 0.42 0.4 Edge Area Edge Area 0.38 100 40 60 80  $Amp_2$ R = $Amp_1 + Amp_2$ 



Distribution of difference between real and reconstructed laser hit position Best spatial resolution: **8.3 µm** 

#### **Position reconstruction:**

- Based on resistor networks, the fraction of the signal (*R*) changes linearly with laser position between gaps.
- Distortion observed at approach to edge region
- Better than 8.3 μm with 150 μm pitch, and approx. 12 μm with 250 μm pitch



- Good consistency between the reconstruction position and the laser position
- The smaller the pitch size, the better the spatial resolution
- The rise in spatial resolution values is slower than linear with increasing Pitch size

## Time resolution of AC-LGAD Strip



- ~ 37 ps timing resolution AC-LGAD, via Beta source test.
- No significant change in timing resolution was observed among pixel, strip AC-LGADs
- Jitter, ~ 15 ps, not change with pitch

$$\sigma_t^2 = \sigma_{TimeWalk}^2 + \sigma_{Landau}^2 + \sigma_{Jitter}^2$$

## LGAD-Strip Spatial resolution



## LGAD-Strip Time Resolution



## Signal Propagation Properties—Transmission Line?



Waveform at different hit positions From P1 to P7

- DC-LGAD with low n+ resistance
- For AC-LGAD and high resistance n+ device, things may change, still need to demostrate.

- transmission line effect
- Skin effect:

Resistance variation with frequency, especially for high frequency signals

- Dielectric Loss: Lost due to dielectric materials
   Total loss is related to frequency
- Signal frequencies mainly in the range of 0.1 to 1.5GHz
- 1GHz dominant
- Amplitudes and areas of waveform (charge) of one end differ, but summation of two ends maintain the same
- In the spectrogram, no significant difference shows in the amplitude of the frequencies among P1-P7

## Application—CEPC ToF





Circular Electron Position Collider (CEPC)—A Higgs factory to run at  $\sqrt{S}$ ~ 240GeV. To produce above 1M Higgs at ZH mode

Tera Z at Z pole mode

- Multi-targets—Higgs, electroweak, flavor physics.....
- LGAD based OTK(+ToF) will be placed between TPC and ECAL
- Time detector is complementary to gaseous detector
- Improve particle separation ability:

--0-4GeV for K/Pi separation, 0-8 GeV for K/p separation

## Application—CEPC ToF









Inner Silicon Tracker (ITK)



Area	~ 70 m <sup>2</sup>
Radius	1.8m
Length	5.8m
Strip Length	20 mm (to be determined)
Strip Pitch	100-500 µm (to be determined)
Channel number	~ $10^7$ channels
MIP Time resolution	~50 ps
Spatial resolution	~ 10 μm (R-Φ)



## **New Trials**

Long strip AC-LGAD simulation ongoingOptimized structure design of AC-LGAD:

• Pixelated AC-LGAD: different pixel size

4.00 3.00 3.00 4.00 5.00 

- Strip AC-LGAD:
  - Different strip length\different pad-pitch size(1cm, 2cm, 4cm long; pitch: 50um to 500um...)
  - Design for endcap region: Sectoral AC-LGAD strip sensors
  - Strip AC-LGAD with different p-stop isolation structure

### Strip DC-LGAD:

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Different strip length\different pad-pitch size(1cm, 2cm, 4cm long; pitch: 50um to 500um...)

### ➢Process parameters design of AC-LGAD:

- AC Coupling capacitor(insulating material)
- N+ layer doping dose



## To do list.....

### ≻(Ideal) Timetable of AC-LGAD:

#### 2024

### Submission 1: end of 2024

--Verification of designing principles and key processes

### 2025



Submission 2: September of 2025

(Testing: IV, CV, timing, spatial resolution, Test beam, radiation hardness)

--Long strip and process optimization

### 2026

#### Submission 3: June of 2026

(Testing: IV, CV, timing, spatial resolution, Test beam, radiation hardness, testing with ASIC)

--Enhancement of irradiation hardness and formation 2027 of detection system

#### Submission 4: June of 2027

--Final version of AC-LGAD for 4D Tracking, achieving time resolution better than 50 ps and position resolution better than 10  $\mu m$  with large sensitive area

• Topic:

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- 1、AC-LGAD simulation, design and fabrication
- 2、AC-LGAD testing: IV, CV, timing, spatial resolution, gain, etc
- 3、AC-LGAD Test beam testing
- 4、Radiation performance (TID, neutron, proton)
- 5、Position reconstruction methods
- 6、Design optimization for electron collider
- 7 Sensor with ASIC(TDC board) testing on system level
- 8、 Application of AC-LGAD as 4D detector

## Collaborations



#### **Cross WG activities**

- <u>WG3</u>- Sensor irradiation performance study
- <u>WG4</u> Simulation of process and structure parameters for fabrication of AC-LGAD
- <u>WG5</u> Beam test to check AC-LGAD timing and spatial performance
- <u>WG6</u>- sensor and ASIC connected methods

### **Cross DRD collaborations**

- <u>DRD4</u>, Photo-Det./PID, AC-LGAD's application as photo detector or X-ray detector
- <u>DRD7</u>, Electronics, AC-LGAD readout ASIC, providing TOA and TOT information, ASIC and sensor testing board

## Summery and Invitation



### Participants for now

Institute of high energy physics, Chinese Academy of Sciences(IHEP)



Institute of Microelectronics, Chinese Academy of Sciences(IME)



Stefan Institute → Jozef Stefan Institute, Ljubljana (JSI)



University of Montenegro (UCG)



≻ Shanghai Jiao Tong University(SJTU)



➤ Shandong University (SDU)



≻ Nankai University (NKU)



Zhengzhou University (ZZU)

- AC-LGAD has the potential to fulfill the requirements of DRD-3 4D tracker in terms of spatial and time resolution, sensitive area fill factor, etc.
- R&D of AC-LGAD has yielded promising results but still has a long way to go.....

## You Are Warmly Invited to Join Us

Contact person:

Prof. Mei Zhao (IHEP-CAS), zhaomei@ihep.ac.cn

Project plan: <a href="https://cds.cern.ch/record/2918306">https://cds.cern.ch/record/2918306</a>

–DRD3–Working Group2 Hybrid Silicon Technologies–DRD3–Working Package2 Sensors for 4D Tracking

# Back up

## Design of the OTK with the strip AC-LGAD: Barrel



# **Mechanical Design for LGAD ToF & OTK**

- Overlap staves for the barrel with detailed electronics design, cooling and installation
  - Sepcial support design to allow precise alignment of the AC-LGAD sensors
  - Extra space for cables
  - Cooling pipes



TPC





**Fig. 4.** The distribution of *I* as a function of momentum for  $K^{\pm}/\pi^{\pm}/p^{(-)}$  (a) and the absolute difference of *I* for  $K^{\pm}/\pi^{\pm}$  and  $K^{\pm}/p^{(-)}$  (b).